DIGITRON SEMICONDUCTORS

1N5985-1N6031 500mW ZENER DIODES

MAXIMUM RATINGS

Operating and Storage Temperature	-65 to +175°C
DC Power Dissipation @ 25°C	
Lead Length 3/8"	500 mW
Derate above 50°C	3.33 mW/°C
Forward Voltage @ 200mA	1.1 V

ELECTRICAL CHARACTERISTICS

Part Number	Nominal Zener Voltage V_Z @ I_{ZT} (note 2) Volts	Zener Test Current I_{ZT} mA	Maximum Zener Impedance (note 1)				Maximum Reverse Leakage Current				Maximum DC Zener Current I_{ZM} (note 3)	Typical Temperature Coefficient of Zener Voltage
			Z_{ZT} @ I_{ZT} Ohms		Z_{ZK} @ I_{ZK} = 0.25mA Ohms		I_{R} @ µA		V_R Volts			
			B,C,D Suffix	A, Non-Suffix	B,C,D Suffix	A, Non-Suffix	B,C,D Suffix	A, Non-Suffix	B,C,D Suffix	A, Non-Suffix	% / °C mA	αVZ % / °C
1N5985	2.4	5.0	100	110	1800	2000	100	100	1.0	0.5	208	-0.09
1N5986	2.7	5.0	100	110	1900	2200	75	100	1.0	0.5	185	-0.075
1N5987	3.0	5.0	95	100	2000	2300	50	100	1.0	0.5	167	-0.07
1N5988	3.3	5.0	95	100	2200	2400	25	75	1.0	0.5	152	-0.06
1N5989	3.6	5.0	90	95	2300	2500	15	50	1.0	0.5	139	-0.055
1N5990	3.9	5.0	90	95	2400	2500	10	25	1.0	1.0	128	-0.045
1N5991	4.3	5.0	88	90	2500	2500	5.0	15	1.0	1.0	116	-0.01
1N5992	4.7	5.0	70	90	2200	2500	3.0	10	1.5	1.0	106	0.01
1N5993	5.1	5.0	50	88	2050	2500	2.0	5.0	2.0	1.0	98	0.025
1N5994	5.6	5.0	25	70	1800	2200	2.0	3.0	3.0	1.5	89	0.035
1N5995	6.2	5.0	10	50	1300	2050	1.0	2.0	4.0	2.0	81	0.04
1N5996	6.8	5.0	8.0	25	750	1800	1.0	2.0	5.2	3.0	74	0.044
1N5997	7.5	5.0	7.0	10	600	1300	0.5	1.0	6.0	4.0	67	0.051
1N5998	8.2	5.0	7.0	15	600	750	0.5	1.0	6.5	5.2	61	0.055
1N5999	9.1	5.0	10	18	600	600	0.1	0.5	7.0	6.0	55	0.061
1N6000	10	5.0	15	22	600	600	0.1	0.5	8.0	6.5	50	0.065
1N6001	11	5.0	18	25	600	600	0.1	0.1	8.4	7.0	45	0.068
1N6002	12	5.0	22	32	600	600	0.1	0.1	9.1	8.0	42	0.073
1N6003	13	5.0	25	36	600	600	0.1	0.1	9.9	8.4	38	0.075
1N6004	15	5.0	32	42	600	600	0.1	0.1	11	9.1	33	0.079
1N6005	16	5.0	36	48	600	600	0.1	0.1	12	9.9	31	0.080
1N6006	18	5.0	42	55	600	600	0.1	0.1	14	11	28	0.083
1N6007	20	5.0	48	62	600	600	0.1	0.1	15	12	25	0.085
1N6008	22	5.0	55	70	600	600	0.1	0.1	17	14	23	0.087
1N6009	24	5.0	62	78	600	600	0.1	0.1	18	15	21	0.090
1N6010	27	5.0	70	88	600	700	0.1	0.1	21	17	19	0.091
1N6011	30	5.0	78	95	600	700	0.1	0.1	23	18	17	0.093
1N6012	33	5.0	88	110	700	800	0.1	0.1	25	21	15	0.094
1N6013	36	5.0	95	130	700	900	0.1	0.1	27	23	14	0.094
1N6014	39	2.0	130	170	800	1000	0.1	0.1	30	25	13	0.095
1N6015	43	2.0	150	180	900	1100	0.1	0.1	33	27	12	0.095
1N6016	47	2.0	170	200	1000	1300	0.1	0.1	36	30	11	0.096
1N6017	51	2.0	180	225	1300	1400	0.1	0.1	39	33	9.8	0.096
1N6018	56	2.0	200	240	1400	1600	0.1	0.1	43	36	8.9	0.096
1N6019	62	2.0	225	265	1400	1700	0.1	0.1	47	39	8.0	0.097
1N6020	68	2.0	240	280	1600	2000	0.1	0.1	52	43	7.4	0.097
1N6021	75	2.0	265	300	1700	2300	0.1	0.1	56	47	6.7	0.098
1N6022	82	2.0	280	350	2000	2600	0.1	0.1	62	52	6.1	0.098
1N6023	91	2.0	300	400	2300	3000	0.1	0.1	69	56	5.5	0.099
1N6024	100	1.0	500	800	2600	4000	0.1	0.1	76	62	5.0	0.110
1N6025	110	1.0	650	950	3000	4500	0.1	0.1	84	69	4.5	0.110
1N6026	120	1.0	800	1250	4000	5000	0.1	0.1	91	76	4.2	0.110
1N6027	130	1.0	950	1400	4500	5500	0.1	0.1	99	84	3.8	0.110
1N6028	150	1.0	1250	1700	5000	6000	0.1	0.1	114	91	3.3	0.110
1N6029	160	1.0	1400	2000	5500	7000	0.1	0.1	122	99	3.1	0.110
1N6030	180	1.0	1700	2350	6000	8000	0.1	0.1	137	114	2.8	0.110
1N6031	200	1.0	2000	2700	7000	9000	0.1	0.1	152	122	2.5	0.110

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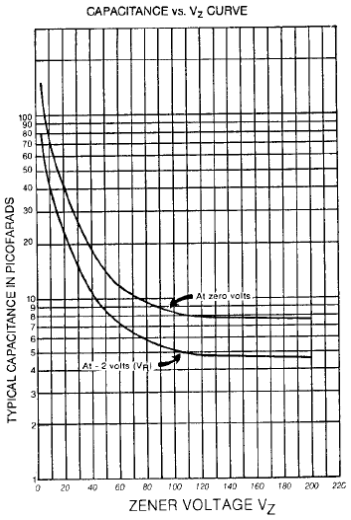
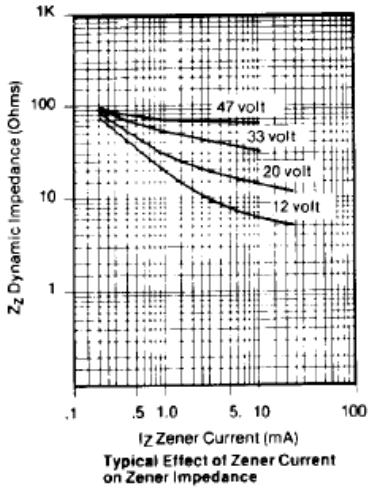
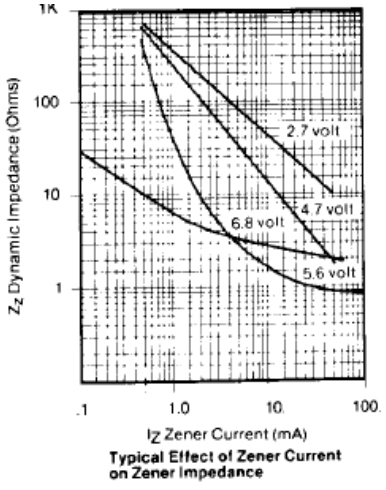
Note 1: Zener impedance is derived from the 1KHz AC voltage which results when an AC current having an rms value equal to 10% of DC zener current (I_{ZT} or I_{ZK}) is superimposed on I_{ZT} or I_{ZK}.
Note 2: Voltage measurements to be performed 20 seconds after application of the DC test current.
Note 3: The maximum zener current IZM is for the nominal voltages. The following formula can be used to determine the worse case current for any tolerance device: $I_{ZM} = P/V_{ZM}$; where V_{ZM} is the high end of the voltage tolerance specified and P is the rated power of the device.





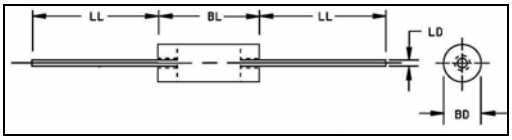
Typical Effect of Zener Current on Zener Impedance



Typical Effect of Zener Current on Zener Impedance

MECHANICAL CHARACTERISTICS

Case:	Hermetically sealed glass DO-35
Polarity:	Cathode band
Marking:	Body Painted, alpha-numeric



	Dimensions			
	Inches		Millimeters	
	Min	Max	Min	Max
BD	-	0.080	-	2.030
BL	-	0.175	-	4.440
LD	0.018	0.022	0.457	0.559
LL	1.000	-	25.400	-

Available Non-RoHS (standard) or RoHS compliant (add PBF suffix).
Available as “HR” (high reliability) screened per MIL-PRF-19500, JANTX level. Add “HR” suffix to base part number.

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